

| | Type | L # | Hits | Search Text | DBs | Time Stamp |
|---|------|-----|------|--|-------------------------------------|---------------------|
| 1 | IS&R | L1 | 2 | ("20040232412").PN. | US-PGPUB; USPAT; EPO; DERWENT | 2005/09/01 15:48 |
| 2 | BRS | L10 | 15 | 7 and (mobility) | US-PGPUB; USPAT; EPO; DERWENT | 2005/09/01 15:57 |
| 3 | IS&R | L2 | 3652 | (257/13,79,94,101,102,103).CCLS. | US-PGPUB; USPAT; EPO; DERWENT | 2005/09/01 15:50 |
| 4 | BRS | L3 | 576 | 2 and (zno mgzno cdzno znas) | US-PGPUB; USPAT; EPO; DERWENT | 2005/09/01 15:51 |
| 5 | BRS | L4 | 17 | 3 and (si silicon) adj wafer | US-PGPUB; USPAT; EPO; DERWENT | 2005/09/01 15:52 |
| 6 | BRS | L5 | 214 | 3 and (mqw ((multi multiple) near3 quantum near3 well)) | US-PGPUB; USPAT; EPO; DERWENT | 2005/09/01 15:54 |
| 7 | BRS | L7 | 84 | 3 and (pn-junction 'pn junction') | US-PGPUB; USPAT; EPO; DERWENT | 2005/09/01 15:55 |
| 8 | BRS | L8 | 13 | 7 and ((dopant doping) adj concentration) | US-PGPUB; USPAT; EPO; DERWENT | 2005/09/01 15:56 |
| 9 | BRS | L9 | 31 | 7 and (resistivity) | US-PGPUB; USPAT; EPO; DERWENT | 2005/09/01 15:57 |

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| 1 | IS&R | L1 | 2 | ("20040232412").PN. | US-PGPUB; USPAT; EPO; DERWENT | 2005/09/01 15:48 |
| 2 | BRS | L10 | 15 | 7 and (mobility) | US-PGPUB; USPAT; EPO; DERWENT | 2005/09/01 15:59 |
| 3 | BRS | L11 | 2 | 3 and (zno mgzno cdzno znas) near5 (pn-junction 'pn junction') | US-PGPUB; USPAT; EPO; DERWENT | 2005/09/01 16:05 |
| 4 | BRS | L12 | 3 | 3 and (zno mgzno cdzno znas) near5 (mqw ((multi multiple) near3 quantum near3 well)) | US-PGPUB; USPAT; EPO; DERWENT | 2005/09/01 16:07 |
| 5 | BRS | L13 | 16 | 3 and (mgzno cdzno znas) | US-PGPUB; USPAT; EPO; DERWENT | 2005/09/01 16:24 |
| 6 | IS&R | L2 | 3652 | (257/13,79,94,101,102,103).CCLS. | US-PGPUB; USPAT; EPO; DERWENT | 2005/09/01 15:50 |
| 7 | BRS | L3 | 576 | 2 and (zno mgzno cdzno znas) | US-PGPUB; USPAT; EPO; DERWENT | 2005/09/01 15:51 |
| 8 | BRS | L4 | 17 | 3 and (si silicon) adj wafer | US-PGPUB; USPAT; EPO; DERWENT | 2005/09/01 16:24 |
| 9 | BRS | L5 | 214 | 3 and (mqw ((multi multiple) near3 quantum near3 well)) | US-PGPUB; USPAT; EPO; DERWENT | 2005/09/01 16:07 |
| 10 | BRS | L7 | 84 | 3 and (pn-junction 'pn junction') | US-PGPUB; USPAT; EPO; DERWENT | 2005/09/01 16:04 |
| 11 | BRS | L8 | 13 | 7 and ((dopant doping) adj concentration) | US-PGPUB; USPAT; EPO; DERWENT | 2005/09/01 15:59 |
| 12 | BRS | L9 | 31 | 7 and (resistivity) | US-PGPUB; USPAT; EPO; DERWENT | 2005/09/01 15:59 |